NSN 5962-01-108-4751

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-108-4751 **Body Length:** Between 1.235 inches and 1.285 inches **Body Width:** Between 0.515 inches and 0.600 inches **Body Height:** Between 0.145 inches and 0.175 inches **Maximum Power Dissipation Rating:** 525.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and low power and programmable and schottky and w/enable and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 350.00 nanoseconds propagation delay time, low to high level output and 350.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

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Yes - demil/mli